HD32012
SOLID STATE HIGH POWER AMPLIFIER

Communications Corp.

FEATURES

Rack mount system
Class AB linear GaN design
Instantaneous ultra-bandwidth
Suitable for all single channel modulations standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	0.8 - 6.0 GHz	
Power Output @ Psat	50 Watt Typ	CW
Power Output @ 1dB GCP	25 Watt Typ	CW
Power Gain	44 dB Min	
Power Gain Flatness	3.0 dB p-p Max	
Input Return Loss	10 dB Min	Relative to 50 Ohm
2-Tone Intermodulation (IMD)	-30 dBc Typ	37dBm/Tone, Δ = 1MHz
Harmonics	-20 dBc Typ	At rated Pout
Non-Harmonics Spurious	-60 dBc Max	
Operating Voltage	100 - 240 VAC	
Power Consumption	300 Watt Max	At rated Pout
Max Input Power Protection	+8 dBm	<10 Sec without damage
Load VSWR Protection	∞ : 1	<1 minute @ rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	No-condensation

MECHANICAL SPECIFICATIONS

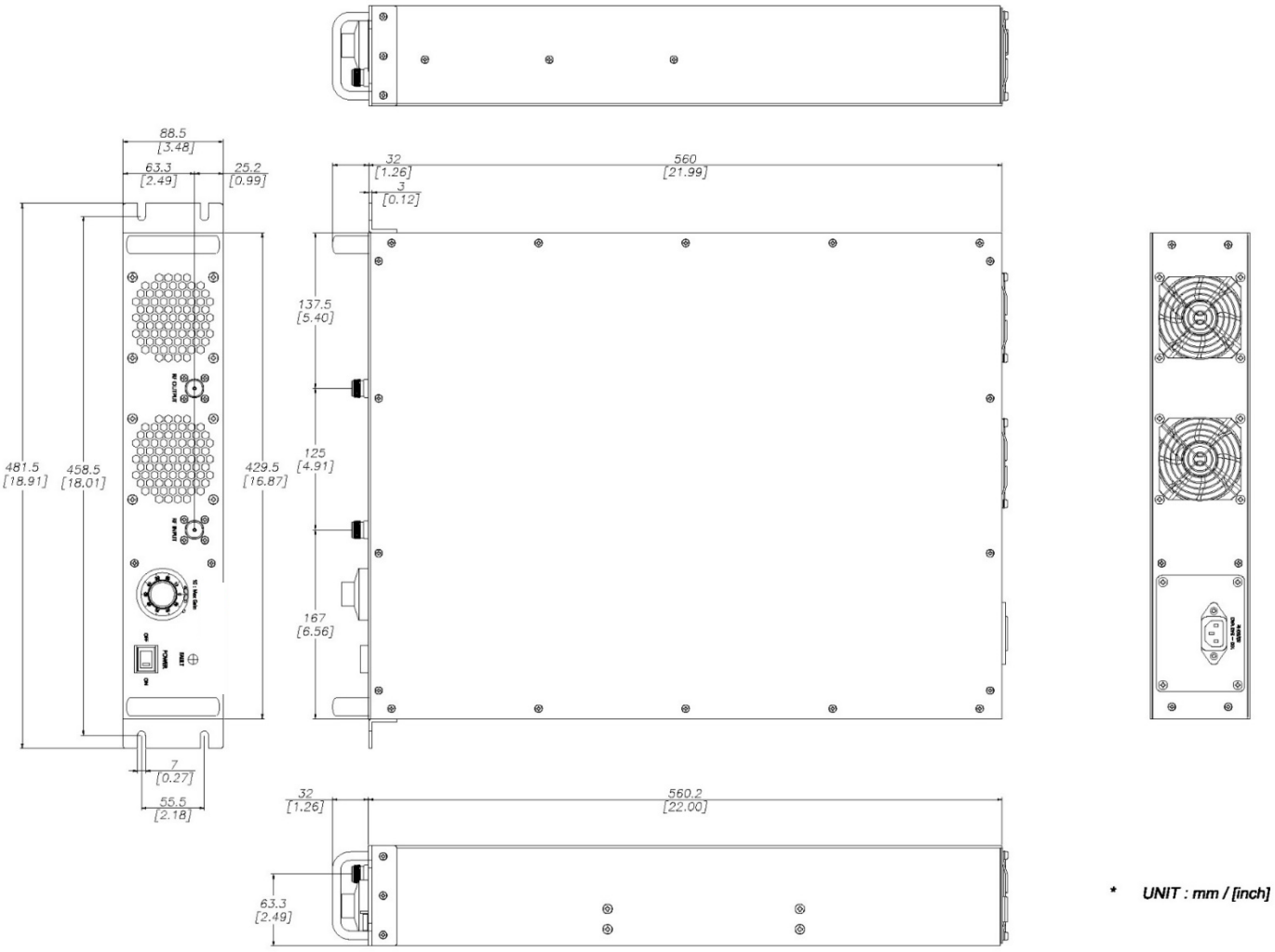
Parameter	Specification	Notes
Dimensions W x H x D	430 x 88 x 562 mm	2U
Weight	10 kg.	
RF Connectors In/Out	Type-N Female	
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, RS422/485	Remote Bluetooth application

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OUTLINE DRAWING



* *UNIT : mm / [inch]*

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